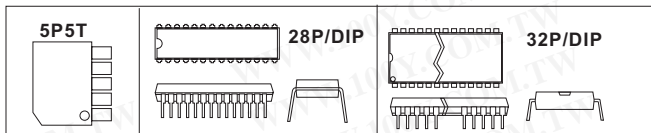


可重覆烧录 EPROM

详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Size (bits)	wordsxbits	Access time (nS)	Program Volt.	Pins/Package	Volt.(Vcc)
19590	M27C4001-12F1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4M	512K*8	120ns	12.75Vpp	32P/FDIP	5V
34828	M27C4001-15F1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4 MBIT	512KB X8	150nS	12.75Vpp	32P/FDIP	5V
34829	M27C4001-45XF1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4 MBIT	512KB X8	45nS	12.75Vpp	32P/FDIP	5V
40129	M27C4001-80XF1	ST(SGS)	4 MBIT (512KB X8) UV EPROM AND OTP ROM	4M	512K*8	80ns	12.75Vpp	32P/FDIP	5V
12956	M27C4002-10F1	ST(SGS)	4 Mbit (256Kb x16) UV EPROM and OTP EPROM	4M	256K*16	100ns	12.75Vpp	32P/DIP	5 V
1449	M27C4002-12F1	ST(SGS)	4 MBIT (256KB X16) UV EPROM AND OTP ROM	4M	256K*16	120ns	12.75Vpp	32P/DIP	5 V
18656	M27C4002-80XF1	ST(SGS)	4 MBIT (256KB X16) UV EPROM AND OTP ROM	4M	256K*16	80ns	12.75Vpp	32P/DIP	5 V
34831	M27C4002-90C1	ST(SGS)	4 Mbit (256Kb x16) UV EPROM and OTP EPROM	4 Mbit	256Kb x16	90nS	12.75Vpp	32P/PLCC	5V
12214	M27C512-10F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	100ns	12.75Vpp	28P/FDIP	5 V
34836	M27C512-12B1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	120nS	12.75Vpp	28P/PDIP	5V
12215	M27C512-12F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	120ns	12.75Vpp	28P/FDIP	5V
34833	M27C512-12XF1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	120nS	12.75Vpp	28P/FDIP	5V
48152	M27C512-15F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	150ns	12.75Vpp	28P/DIP	5V
34835	M27C512-15XF1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	150nS	12.75Vpp	28P/FDIP	5V
34837	M27C512-45XF1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	45nS	12.75Vpp	28P/FDIP	5V
34838	M27C512-70C1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	70nS	12.75Vpp	32P/PLCC	5V
40217	M27C512-70F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 KBIT	64KB X8	70nS		FDIP28W	
14113	M27C512-90F1	ST(SGS)	512 KBIT (64KB X8) UV EPROM AND OTP EPROM	512 K	64K*8	90ns	12.75Vpp	28P/DIP	5V
28752	M27C64A-12F1	ST(SGS)	可重复烧录 EPROM	512 K	64Kb x8	45ns	12.75V ± 0.25V	28P/DIP	-2~ 7V
1422	M27C64A-15F1	ST(SGS)	64 Kilobit (8 K x 8-Bit) CMOS	64K	8K*8	150ns	12.5Vpp	28P/DIP	5 V
34844	M27C64A-20F6	ST(SGS)	64 Kbit (8Kb x 8) UV EPROM and OTP EPROM	64 Kbit	8Kb x 8	200nS	12.5Vpp	28P/DIP	5V
34847	M27C64A-30F1	ST(SGS)	64 Kbit (8Kb x 8) UV EPROM and OTP EPROM	64 Kbit	8Kb x 8	300nS	12.5Vpp	28P/DIP	5V
1450	M27C801-100F1	ST(SGS)	8 MBIT (1MB X 8) UV EPROM AND OTP EPROM	8M	1M*8	100ns	12.75Vpp	32P/DIP	5 V
46332	M27C801-100F6	ST(SGS)	可重复烧录 EPROM	8M	1M*8	100ns	12.75Vpp	32P/DIP	5V
18658	M27C801-120F1	ST(SGS)	8 MBIT (1MB X 8) UV EPROM AND OTP EPROM	8M	1M*8	120ns	12.75Vpp	32P/DIP	5 V
34848	M27W101-80K6	ST(SGS)	1 Mbit (128Kb x8) Low Voltage UV EPROM and OTP EPROM	1 Mbit	128Kb x8	80nS		32P/PLCC	2.7V to 3.6V
19329	M51957BL	MITSUBISHI	可重复烧录 EPROM					5P5T	2~17V
17150	M5M27C102K-12	MITSUBISHI	1M EPROM 120nS	1M(*16)	65536*16	120nS	12.5Vpp	40P/DIP	5V
19375	MB8516	FUJITSU	可重复烧录 EPROM					DIP	
14204	MBM27C128-20	FUJITSU	EPROM 16K*8 DIP	128K	16K*8	200ns		28P/DIP	5V
22743	MX27C1000QC-15	MXIC	CMOS EPROM	128K*8	1M	150nS	12.5V	32P/PLCC	5V
22744	MX27C256QC-15	MXIC	CMOS EPROM	256K	32K*8	150nS	12.5V	32P/PLCC	5V
22749	MX27C8000QC-12	MXIC	CMOS EPROM	1M*8	8M	120nS	12.5V	32P/PLCC	5V
22750	MX27L2000PC-15	MXIC	CMOS EPROM	256K*8	2M	150nS	12.5V	32P/DIP	2.7~3.6V
18663	NM27C010Q200	N.S	1M-Bit CMOS EPROM	1M	128K*8	200nS	12.75Vpp	32P/DIP	5V
23226	NM27C256Q150	N.S	可重复烧录 EPROM	256K	32K*8	150	12.75Vpp	DIP	5V
1465	NM27C256Q90	Fairchild	262,144-Bit (32K x 8) High Performance CMOS EPROM	256K	32K*8	90nS	12.75Vpp	28P/DIP	5V
23599	NM27C256V150	N.S	High Performance CMOS EPROM	32K * 8	256K	150ns		32P/PLCC	5V+/-10%
18672	NM27C256V200	N.S	262,144-Bit (32K x 8) High Performance CMOS EPROM	262,144	32K*8	200ns	12.75Vpp	32P/PLCC	5V
1467	NM27C512Q150	N.S	EPROM 64K*8 DIP	512K	64K*8	150ns	12.75Vpp	28P/DIP	5 V
1472	NMC27C64Q150	N.S	可重复烧录 EPROM	64K	8K*8	150ns	12.75Vpp	DIP	5V
1473	NMC27C64Q200	N.S	可重复烧录 EPROM	64K	8K*8	200	12.75	DIP	5
18673	P27C220-150V05	INTEL	2M-BIT [256Kx8/128x16] CMOS EPROM	2M	256Kx8 or 128x16	150ns	12.5Vpp	40P/DIP	5V
18674	TMS27C020-12JE	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	2M	256K*8	120ns	12.75Vpp	32P/DIP	5 V
1475	TMS27C020-12JL	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	2M	256K*8	120ns	12.75Vpp	32P/DIP	5 V
18675	TMS27C020-15JL	ST(SGS)	PROGRAMMABLE READ-ONLY MEMORIES	2M	256K*8	150ns	12.75Vpp	32P/DIP	5 V
32188	TMS27C210A-15	T.I.	EPROM	1048576 bits	65536 * 16-bit	150ns	13Vpp	40P/DIP	5V
22854	TMS27C240-10JL	T.I.	4M EPROM	4M	222144 by 16Bit	100nS	13Vpp	40P/DIP	5V
32187	TMS27C240-12	T.I.	4M EPROM	4M	262144 by 16Bit	120ns	13Vpp	40P/DIP	5V
18676	TMS27C256-12JL	ST(SGS)	READ-ONLY MEMORY	256K	32K*8	120ns	12.5Vpp	32P/DIP	5 V
3196	TMS27C512-10JL	T.I.	PROGRAMMABLE READ-ONLY MEMORIES	512K	64K*8	100nS	12.75Vpp	28P/DIP	5V
18677	TMS27PC128-1NL	ST(SGS)	READ-ONLY MEMORY	128K	16K*8	150ns	12.5Vpp	28P/DIP	5 V
1484	UPD27C1024AD-20	NEC	1M-BIT [128K x 8/64K x 16] CMOS EPROM	1M	64K*16	200ns	12.75Vpp	40P/DIP	5 V
15277	W27C257-10	WINBOND	Electrically Erasable EPROM	256K	32K*8	100nS	12Vpp	28P/DIP	5 V
18678	W27C512-45	WINBOND	Electrically Erasable EPROM	512K	64K*8	45ns	12Vpp	28P/DIP	5 V
1433	W27C512-45Z	WINBOND	Electrically Erasable EPROM	512K	64K*8	45ns	12Vpp	28P/DIP	5 V
23150	W27C512P-70	WINBOND	ELECTRICALLY ERASABLE EPROM	64K*8	512K	70nS		32P/PLCC	5V
16558	W27E010-70	WINBOND	1M Electrically Erasable EPROM	128K*8	128K*8	70nS	12Vpp	32P/DIP	5 V
15308	W27E010P-70	WINBOND	1MB Electrically Erasable EPROM	1M	128K*8	70nS	12Vpp	32P/PLCC	5 V



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